TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA79L005P,TA79L006P,TA79L008P,TA79L009P,TA79L010P, TA79L012P,TA79L015P,TA79L018P,TA79L020P,TA79L024P

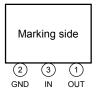
-5 V, -6 V, -8 V, -9 V, -10 V, -12 V, -15 V, -18 V, -20 V, -24 V

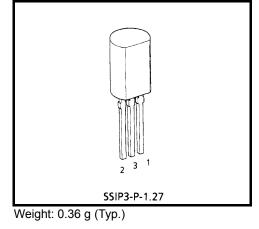
Three-Terminal Negative Voltage Regulators

Features

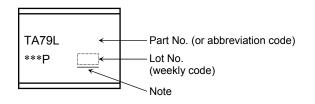
- Best suited to a power supply for TTL and C^2MOS .
- Built-in overcurrent protection.
- Built-in overheating protection.
- Maximum output current of 150 mA (T_j = 25°C).
- Packaged in TO-92MOD.

Pin Assignment





Marking



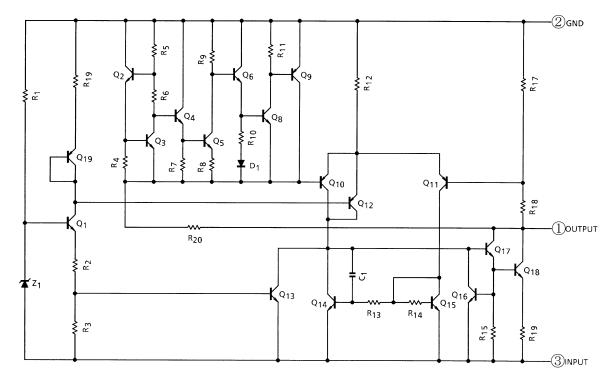
Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

The product(s) in this document ("Product") contain functions intended to protect the Product from temporary small overloads such as minor short-term overcurrent or overheating. The protective functions do not necessarily protect Product under all circumstances. When incorporating Product into your system, please design the system (1) to avoid such overloads upon the Product, and (2) to shut down or otherwise relieve the Product of such overload conditions immediately upon occurrence. For details, please refer to the notes appearing below in this document and other documents referenced in this document.

TOSHIBA

Equivalent Circuit



Absolute Maximum Ratings (Ta = 25°C)

Characteris	tics	Symbol	Rating	Unit
	TA79L005P			
	TA79L006P			
	TA79L008P			
	TA79L009P		-35	
Input voltago	TA79L010P	Max		V
Input voltage	TA79L012P	V _{IN}		v
	TA79L015P			
	TA79L018P			
	TA79L020P		-40	
	TA79L024P			
Output current		IOUT	0.15	А
Power dissipation	(Ta = 25°C)	PD	800	mW
Operating temperature		T _{opr}	−30 to 85	°C
Storage temperature		T _{stg}	-55 to 150	°C
Junction temperature		Tj	150	°C
Thermal resistance		R _{th (j-a)}	156	°C/W

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

TA79L005P Electrical Characteristics (Unless otherwise specified, V_{IN} = -10 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-5.2	-5.0	-4.8	V
Line regulation	Degline	1	$T_{\rm c} = 25^{\circ}$ C	-20 V ≤ V _{IN} ≤ -7.0 V	_	55	150	mV
Line regulation	Reg·line	I	T _j = 25°C	-20 V ≤ V _{IN} ≤ -8.0 V	_	45	100	mv
Lood regulation	Declard	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	11	60	mV
Load regulation	Reg·load	I	$1_{j} = 25 C$	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	5.0	30	mv
Output voltage	Vout	1	T _i = 25°C	−20 V ≤ V _{IN} ≤ −7.0 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-5.25	_	-4.75	V
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-5.25	—	-4.75	
Quiescent current	1_	1	T _j = 25°C		_	3.1	6.0	m (
Quiescent current	Ι _Β	1	T _j = 125°C	25°C		—	5.5	mA
Ouissant summat shares	Δl _{Bl}	1	T - 25°0	$-20 \text{ V} \le \text{V}_{\text{IN}} \le -8.0 \text{ V}$	_	—	1.5	A
Quiescent current change	Δl _{BO}	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	—	0.1	mA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	40	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	12	_	mV/kh
Ripple rejection ratio	R.R.	3	−18 V ≤ V _{IN} ≤ −8.0 V, T _j = 25°C, f = 120 Hz		41	49	_	dB
Dropout voltage	VD	1	T _j = 25°C		_	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	0.6	_	mV/°C

TA79L006P Electrical Characteristics (Unless otherwise specified, V_{IN} = -11 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-6.24	-6.0	-5.76	V
Line regulation	Reg·line	1	T _i = 25°C	-21 V ≤ V _{IN} ≤ -8.1 V	_	50	150	mV
	Regiline	1	1j = 25 C	-21 V ≤ V _{IN} ≤ -9.0 V	_	45	110	IIIV
Load regulation	Reg·load	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	12	70	mV
	Regillau	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	5.5	35	IIIV
Output voltage	Vout	1	T _i = 25°C	−21 V ≤ V _{IN} ≤ −8.1 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-6.3	_	-5.7	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-6.3		-5.7	
Quiescent current	1-	1	T _j = 25°C		_	3.1	6.0	mA
	IB	I	T _j = 125°C	;	_		5.5	ma
Quieseent eurrent change	Δl _{Bl}	1	T _i = 25°C	-21 V ≤ V _{IN} ≤ -9.0 V	_		1.5	mA
Quiescent current change	ΔI _{BO}	1	$1_{j} = 25 C$	1.0 mA ≤ I _{OUT} ≤ 40 mA	_		0.1	ma
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	40	—	μV_{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	14	—	mV/kh
Ripple rejection ratio	R.R.	3	−19 V ≤ V _{IN} ≤ −9.0 V, T _j = 25°C, f = 120 Hz		39	47	_	dB
Dropout voltage	VD	1	T _j = 25°C		_	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	l _{OUT} = 5 r	nA	_	0.7	_	mV/°C

TA79L008P Electrical Characteristics (Unless otherwise specified, V_{IN} = -14 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-8.3	-8.0	-7.7	V
Line regulation	Degline	1	$T_{\rm c} = 25^{\circ}$ C	-23 V ≤ V _{IN} ≤ -10.5 V	_	20	175	mV
Line regulation	Reg·line	I	T _j = 25°C	-23 V ≤ V _{IN} ≤ -11 V	_	12	125	mv
Lood regulation	Declard	1	$T_{\rm c} = 25^{\circ}$ C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	15	80	mV
Load regulation	Reg·load	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	7.0	40	mv
Output voltage	Vout	1	T _i = 25°C	−23 V ≤ V _{IN} ≤ −10.5 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-8.4	_	-7.6	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-8.4	_	-7.6	I
Quiescent current	1_	1	T _j = 25°C		_	3.1	6.5 mA	m 4
Quiescent current	Ι _Β	I	T _j = 125°C)	_	_	6.0	ma
Ouissant summat shares	Δl _{Bl}	1	T - 25°C	-23 V ≤ V _{IN} ≤ -11 V	_	_	1.5	
Quiescent current change	Δl _{BO}	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	mA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	60	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	20	_	mV/kh
Ripple rejection ratio	R.R.	3	$-23 V \le V_{IN} \le -12 V$, T _j = 25°C, f = 120 Hz		37	45	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	0.8	_	mV/°C

TA79L009P Electrical Characteristics (Unless otherwise specified, $V_{IN} = -15$ V, $I_{OUT} = 40$ mA, $C_{IN} = 0.33$ µF, $C_{OUT} = 0.1$ µF, $0^{\circ}C \leq T_j \leq 125^{\circ}C$)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-9.36	-9.0	-8.64	V
Line regulation	Degline	1	$T_{\rm c} = 25^{\circ}$ C	-24 V ≤ V _{IN} ≤ -11.4 V	_	80	200	mV
Line regulation	Reg·line		T _j = 25°C	$-24 \text{ V} \leq \text{V}_{IN} \leq -12 \text{ V}$	_	20	160	mv
Lood regulation	Declard	4	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	17	90	mV
Load regulation	Reg·load	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	8.0	45	mv
Output voltage	Vout	1	T _i = 25°C	−24 V ≤ V _{IN} ≤ −11.4 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-9.45	_	-8.55	V
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-9.45	_	-8.55	
Quiescent current	1-	1	T _j = 25°C		_	3.2	6.5	mA
Quiescent current	Ι _Β		T _j = 125°C)	_	_	6.0	ma
Quiescent current change	ΔI _{BI}	1	$T_{\rm c} = 25^{\circ}$ C	-24 V ≤ V _{IN} ≤ -12 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	ma
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	65	_	μV_{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	21	_	mV/kh
Ripple rejection ratio	R.R.	3	-24 V ≤ V T _j = 25°C,	IN ≤ −12 V, f = 120 Hz	36	44	_	dB
Dropout voltage	VD	1	T _j = 25°C		_	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	l _{OUT} = 5 r	nA	_	0.85	_	mV/°C

TA79L010P Electrical Characteristics (Unless otherwise specified, V_{IN} = -16 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-10.4	-10.0	-9.6	V
Line regulation	Degline	1	T _i = 25°C	−25 V ≤ V _{IN} ≤ −12.5 V	_	80	230	mV
Line regulation	Reg·line	1	1j = 25 C	-25 V ≤ V _{IN} ≤ -13 V	_	30	170	IIIV
Load regulation	Bogulood	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	18	90	mV
Load regulation	Reg·load	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	8.5	45	IIIV
Output voltage	Vout	1	T _i = 25°C	−25 V ≤ V _{IN} ≤ −12.5 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-10.5	_	-9.5	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-10.5	_	-9.5	
Quiescent current	1-	1	T _j = 25°C		_	3.2	6.5	mA
	IB	1	T _j = 125°C	;	_	_	6.0	IIIA
Quiessent aurrent abange	ΔI _{BI}	1	T _i = 25°C	-25 V ≤ V _{IN} ≤ -13 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	1 - 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	IIIA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	70		μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	22		mV/kh
Ripple rejection ratio	R.R.	3	$-24 V \le V_{IN} \le -13 V$, T _j = 25°C, f = 120 Hz		36	43	_	dB
Dropout voltage	VD	1	T _j = 25°C		-	1.7	_	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	0.9		mV/°C

TA79L012P Electrical Characteristics (Unless otherwise specified, V_{IN} = -19 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	VOUT	1	T _j = 25°C		-12.5	-12.0	-11.5	V
Line regulation	Pogulino	1	T _i = 25°C	−27 V ≤ V _{IN} ≤ −14.5 V	_	120	250	mV
Line regulation	Reg·line	1	1j = 25 C	−27 V ≤ V _{IN} ≤ −16 V	_	100	200	IIIV
Load regulation	Pearload	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	20	100	mV
Load regulation	Reg·load	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	10	50	IIIV
Output voltage	Vout	1	T _i = 25°C	−27 V ≤ V _{IN} ≤ −14.5 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-12.6	_	-11.4	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-12.6	_	-11.4	
Quiescent current	1-	1	T _j = 25°C		_	3.2	6.5	mA
	Ι _Β	1	T _j = 125°C	;	_	_	6.0	mA
Quiessent aurrent abange	ΔI _{BI}	1	T _i = 25°C	−27 V ≤ V _{IN} ≤ −16 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	mA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	80	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	24	_	mV/kh
Ripple rejection ratio	R.R.	3	−25 V ≤ V _{IN} ≤ −15 V, T _j = 25°C, f = 120 Hz		37	42	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	_	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	1.0	_	mV/°C

TA79L015P Electrical Characteristics (Unless otherwise specified, V_{IN} = -23 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C	T _j = 25°C		-15.0	-14.4	V
Line regulation	Degline	1	T _i = 25°C	−30 V ≤ V _{IN} ≤ −17.5 V	_	130	300	mV
Line regulation	Reg·line	1	1j = 25 C	-30 V ≤ V _{IN} ≤ -20 V	_	110	250	IIIV
Load regulation	Reg·load	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	25	150	mV
	Regiloau	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	12	75	IIIV
Output voltage	Vout	1	T _i = 25°C	−30 V ≤ V _{IN} ≤ −17.5 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-15.75	_	-14.25	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-15.75	_	-14.25	
Quiescent current	1-	1	T _j = 25°C		_	3.3	6.5	mA
	IB	1	T _j = 125°C	;	_	_	6.0	IIIA
Quicecont ourrent change	ΔI _{BI}	1	T _i = 25°C	-30 V ≤ V _{IN} ≤ -20 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	IIIA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	90	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	30	_	mV/kh
Ripple rejection ratio	R.R.	3	$-28.5 V \le V_{IN} \le -18.5 V$, T _j = 25°C, f = 120 Hz		34	39	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	_	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	1.3	_	mV/°C

TA79L018P Electrical Characteristics (Unless otherwise specified, V_{IN} = -27 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-18.7	-18.0	-17.3	V
Line regulation	Degline	1	$T_{\rm c} = 25^{\circ}$ C	-33 V ≤ V _{IN} ≤ 20.7 V	_	32	325	mV
Line regulation	Reg·line	I	T _j = 25°C	-33 V ≤ V _{IN} ≤ -21 V	_	27	275	mv
Lood regulation	Declard	1	$T_{\rm c} = 25^{\circ}$ C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	30	170	mV
Load regulation	Reg·load	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	15	75	mv
Output voltage	Vout	1	T _i = 25°C	−33 V ≤ V _{IN} ≤ −20.9 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-18.9	_	-17.1	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-18.9	_	-17.1	
Quiescent current	1_	1	T _j = 25°C		_	3.3	6.5	mA
	Ι _Β	I	T _j = 125°C	;	_	_	6.0	ma
Quiescent current change	Δl _{Bl}	1	T _i = 25°C	-33 V ≤ V _{IN} ≤ -21 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	$1_{j} = 25 C$	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	ma
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	150	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	45	_	mV/kh
Ripple rejection ratio	R.R.	3	$-33 V \le V_{IN} \le -23 V$, T _j = 25°C, f = 120 Hz		33	48	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	1.5	_	mV/°C

TA79L020P Electrical Characteristics (Unless otherwise specified, V_{IN} = -29 V, I_{OUT} = 40 mA, C_{IN} = 0.33 μ F, C_{OUT} = 0.1 μ F, 0°C \leq T_j \leq 125°C)

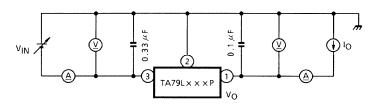
Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-20.8	-20.0	-19.2	V
Line regulation	Degline	1	$T_{\rm c} = 25^{\circ}$ C	-35 V ≤ V _{IN} ≤ -23.5 V	_	33	330	mV
Line regulation	Reg·line	I	T _j = 25°C	-35 V ≤ V _{IN} ≤ -24 V	_	28	285	mv
Lood regulation	Declard	1	$T_{\rm c} = 25^{\circ}$ C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	33	180	mV
Load regulation	Reg·load	1	T _j = 25°C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	17	90	mv
Output voltage	Vout	1	T _i = 25°C	−35 V ≤ V _{IN} ≤ −23.5 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-21.0	_	-19.0	v
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-21.0	_	-19.0	
Quiescent current	1_	1	T _j = 25°C		_	3.3	6.5	m 4
Quiescent current	Ι _Β	1	T _j = 125°C	;	_	_	6.0	mA
Ouissesst surrent shares	Δl _{Bl}	1	T _i = 25°C	-35 V ≤ V _{IN} ≤ -24 V	_	_	1.5	mA
Quiescent current change	Δl _{BO}	1	$1_{j} = 25 C$	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	ma
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	170	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	49	_	mV/kh
Ripple rejection ratio	R.R.	3	−35 V ≤ V _{IN} ≤ −27 V, T _j = 25°C, f = 120 Hz		31	37	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	_	1.7	_	mV/°C

TA79L024P Electrical Characteristics (Unless otherwise specified, $V_{IN} = -33$ V, $I_{OUT} = 40$ mA, $C_{IN} = 0.33$ µF, $C_{OUT} = 0.1$ µF, $0^{\circ}C \leq T_{j} \leq 125^{\circ}C$)

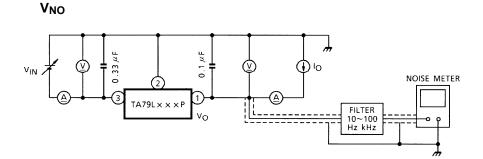
Characteristics	Symbol	Test Circuit		Test Condition	Min	Тур.	Max	Unit
Output voltage	V _{OUT}	1	T _j = 25°C		-25.0	-24.0	-23.0	V
Line regulation	Degline	1	T _i = 25°C	-38 V ≤ V _{IN} ≤ -27 V	_	35	350	mV
Line regulation	Reg·line	I	$1_{j} = 25 C$	-38 V ≤ V _{IN} ≤ -28 V	_	30	300	mv
Lood regulation	Declard	1	T _i = 25°C	1.0 mA ≤ I _{OUT} ≤ 100 mA	_	40	200	mV
Load regulation	Reg·load	I	$1_{j} = 25 C$	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	20	100	mv
Output voltage	Vout	1	T _i = 25°C	−38 V ≤ V _{IN} ≤ −27 V, 1.0 mA ≤ I _{OUT} ≤ 40 mA	-25.2	_	-22.8	V
			,	1.0 mA ≤ I _{OUT} ≤ 70 mA	-25.2	_	-22.8	
Quiescent current	1-	1	T _j = 25°C		_	3.5	6.5	mA
	Ι _Β	1	T _j = 125°C	125°C		_	6.0	IIIA
Quiescent current change	ΔI _{BI}	1	T _i = 25°C	-38 V ≤ V _{IN} ≤ -28 V	_	_	1.5	mA
Quiescent current change	ΔI _{BO}	1	1j = 25 C	1.0 mA ≤ I _{OUT} ≤ 40 mA	_	_	0.1	IIIA
Output noise voltage	V _{NO}	2	Ta = 25°C	, 10 Hz ≤ f ≤ 100 kHz	_	200	_	μV _{rms}
Long term stability	ΔV _{OUT} /Δt	1		_	_	56	_	mV/kh
Ripple rejection ratio	R.R.	3	$-35 \text{ V} \le \text{V}_{IN} \le -29 \text{ V},$ T _j = 25°C, f = 120 Hz		31	47	_	dB
Dropout voltage	VD	1	T _j = 25°C		—	1.7	—	V
Average temperature coefficient of output voltage	T _{CVO}	1	I _{OUT} = 5 n	nA	—	2.0	_	mV/°C

Test Circuit 1

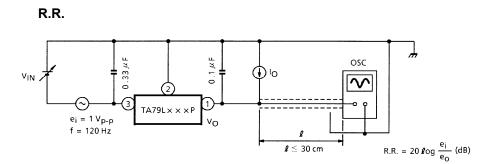
 $V_{OUT}, Reg \cdot line, Reg \cdot load, I_B, \Delta I_B, \Delta V_{OUT} / \Delta t, V_D, T_{CVO}$



Test Circuit 2



Test Circuit 3



Usage Precautions

• Low voltage

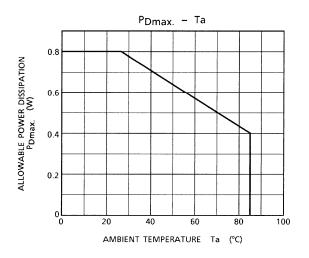
Do not apply voltage to the Product that is lower than the minimum operating voltage, or the Product's protective functions will not operate properly and the Product may be permanently damaged.

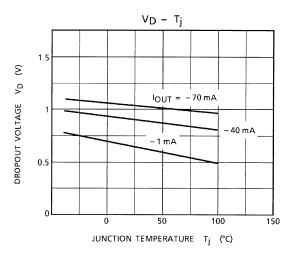
Overcurrent Protection

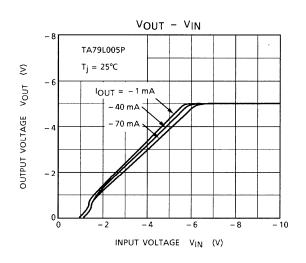
The overcurrent protection circuits in the Product are designed to temporarily protect Product from minor overcurrent of brief duration. When the overcurrent protective function in the Product activates, immediately cease application of overcurrent to Product. Improper usage of Product, such as application of current to Product exceeding the absolute maximum ratings, could cause the overcurrent protection circuit not to operate properly and/or damage Product permanently even before the protection circuit starts to operate.

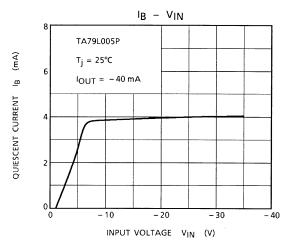
Overheating Protection

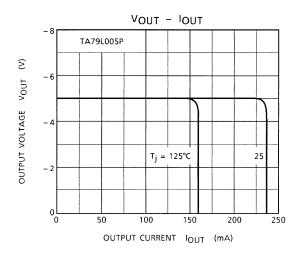
The thermal shutdown circuits in the Product are designed to temporarily protect Product from minor overheating of brief duration. When the overheating protective function in the Product activates, immediately correct the overheating situation. Improper usage of Product, such as the application of heat to Product exceeding the absolute maximum ratings, could cause the overheating protection circuit not to operate properly and/or damage Product permanently even before the protection circuit starts to operate.







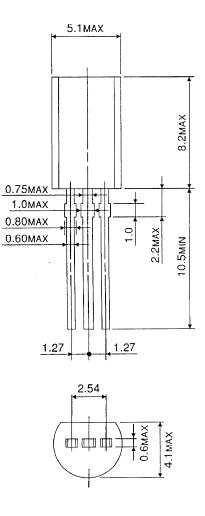




Package Dimensions

SSIP3-P-1.27

Unit : mm



Weight : 0.36 g (Typ.)

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